

1. Record Nr.	UNINA9910710101003321
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Titolo	Resistivity and carrier lifetime in gold-doped silicon / / W. Robert Thurber; David C. Lewis; W. Murray Bullis
Pubbl/distr/stampa	Gaithersburg, MD : , : U.S. Dept. of Commerce, National Institute of Standards and Technology, , 1973
Descrizione fisica	1 online resource
Collana	NBSIR ; ; 73-128
Altri autori (Persone)	BullisW. Murray LewisDavid C ThurberW. Robert
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	1973. Contributed record: Metadata reviewed, not verified. Some fields updated by batch processes. Title from PDF title page.
Nota di bibliografia	Includes bibliographical references.